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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	ARM® Cortex®-M0
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I <sup>2</sup> C, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, I <sup>2</sup> S, POR, PWM, WDT
Number of I/O	26
Program Memory Size	200KB (200K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 16x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	38-TFSOP (0.173", 4.40mm Width)
Supplier Device Package	PG-TSSOP-38-9
Purchase URL	<a href="https://www.e-xfl.com/product-detail/infineon-technologies/xmc1201t038f0200abxuma1">https://www.e-xfl.com/product-detail/infineon-technologies/xmc1201t038f0200abxuma1</a>

**Edition 2016-08**

**Published by  
Infineon Technologies AG  
81726 Munich, Germany**

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## On-Chip Debug Support

- Support for debug features: 4 breakpoints, 2 watchpoints
- Various interfaces: ARM serial wire debug (SWD), single pin debug (SPD)

## 1.1 Ordering Information

The ordering code for an Infineon microcontroller provides an exact reference to a specific product. The code "XMC1<DDD>-<Z><PPP><T><FFFF>" identifies:

- <DDD> the derivatives function set
- <Z> the package variant
  - T: TSSOP
  - Q: VQFN
- <PPP> package pin count
- <T> the temperature range:
  - F: -40°C to 85°C
  - X: -40°C to 105°C
- <FFFF> the Flash memory size.

For ordering codes for the XMC1200 please contact your sales representative or local distributor.

This document describes several derivatives of the XMC1200 series, some descriptions may not apply to a specific product. Please see [Table 1](#).

For simplicity the term **XMC1200** is used for all derivatives throughout this document.

## 1.2 Device Types

These device types are available and can be ordered through Infineon's direct and/or distribution channels.

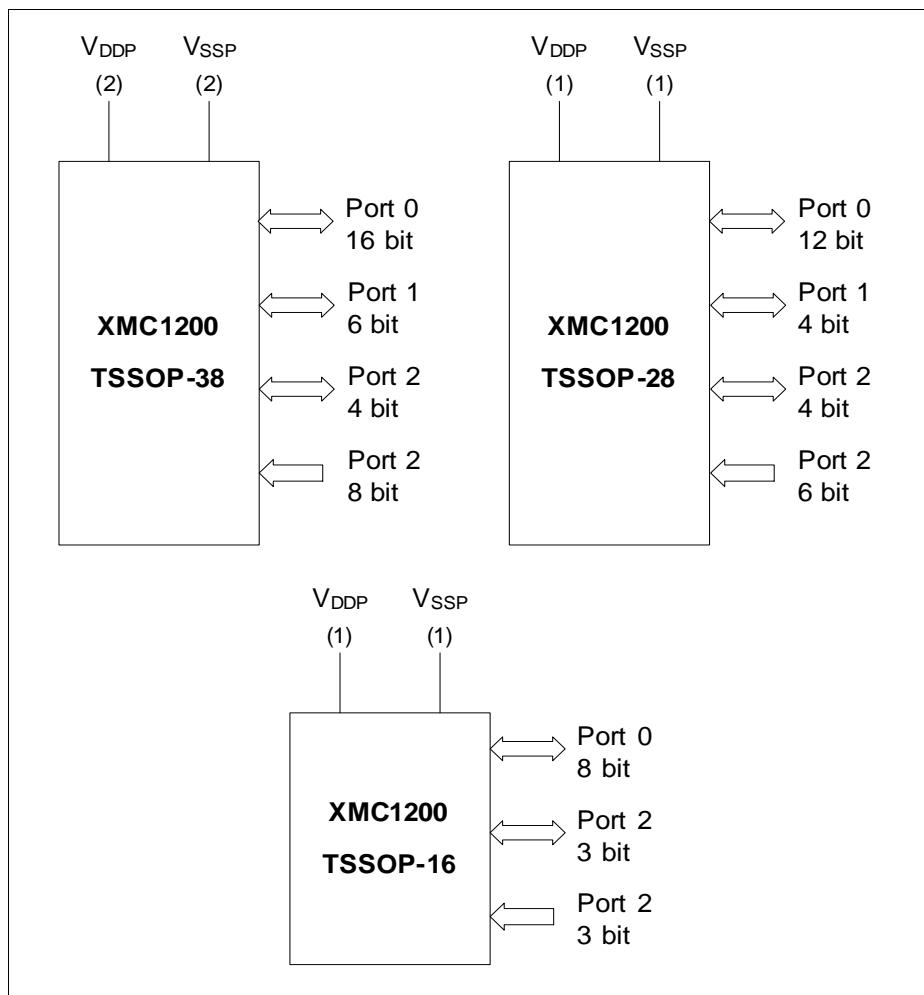
**Table 1 Synopsis of XMC1200 Device Types**

Derivative	Package	Flash Kbytes	SRAM Kbytes
XMC1201-T028F0016	PG-TSSOP-28-16	16	16
XMC1201-T028F0032	PG-TSSOP-28-16	32	16
XMC1201-T038F0016	PG-TSSOP-38-9	16	16
XMC1201-T038F0032	PG-TSSOP-38-9	32	16
XMC1201-T038F0064	PG-TSSOP-38-9	64	16
XMC1201-T038F0128	PG-TSSOP-38-9	128	16
XMC1201-T038F0200	PG-TSSOP-38-9	200	16
XMC1200-T038F0200	PG-TSSOP-38-9	200	16

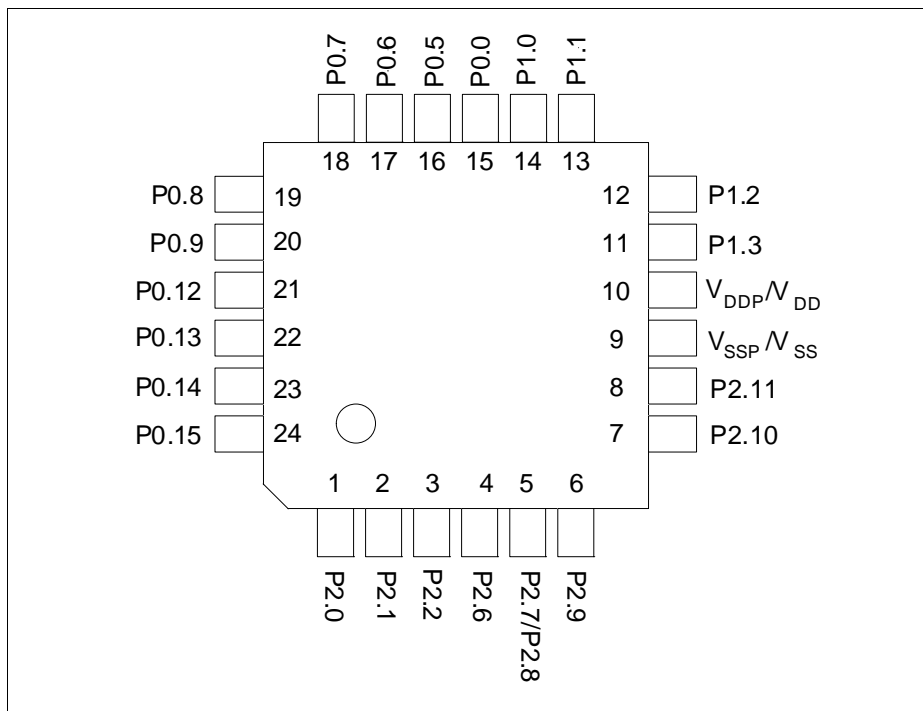
## 2 General Device Information

This section summarizes the logic symbols and package pin configurations with a detailed list of the functional I/O mapping.

### 2.1 Logic Symbols



**Figure 2 XMC1200 Logic Symbol for TSSOP-38, TSSOP-28 and TSSOP-16**



**Figure 7 XMC1200 PG-VQFN-24 Pin Configuration (top view)**

## 2.2.1 Package Pin Summary

The following general building block is used to describe each pin:

**Table 5 Package Pin Mapping Description**

Function	Package A	Package B	...	Pad Type
Px.y	N	N		Pad Class

The table is sorted by the “Function” column, starting with the regular Port pins (Px.y), followed by the supply pins.

The following columns, titled with the supported package variants, lists the package pin number to which the respective function is mapped in that package.

The “Pad Type” indicates the employed pad type:

- STD\_INOUT (standard bi-directional pads)
- STD\_INOUT/AN (standard bi-directional pads with analog input)
- High Current (high current bi-directional pads)
- STD\_IN/AN (standard input pads with analog input)
- Power (power supply)

Details about the pad properties are defined in the Electrical Parameters.

**Table 6 Package Pin Mapping**

Function	VQFN 40	TSSOP 38	TSSOP 28	VQFN 24	TSSOP 16	Pad Type	Notes
P0.0	23	17	13	15	7	STD_INOUT	
P0.1	24	18	-	-	-	STD_INOUT	
P0.2	25	19	-	-	-	STD_INOUT	
P0.3	26	20	-	-	-	STD_INOUT	
P0.4	27	21	14	-	-	STD_INOUT	
P0.5	28	22	15	16	8	STD_INOUT	
P0.6	29	23	16	17	9	STD_INOUT	

**Table 9 Port I/O Functions**

Function	Outputs							Inputs							
	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	Input	Input	Input	Input	Input	Input	Input	Input
P0.0	ERU0. P0OUT0	LEDTS0. LINE7	ERU0. GOUT0	CCU40. OUT0		USIC0_CH 0.SELO0	USIC0_CH 1.SELO0	BCCU0. TRAPINB	CCU40.IN0 C			USIC0_CH 0.DX2A	USIC0_CH 1.DX2A		
P0.1	ERU0. P0OUT1	LEDTS0. LINE6	ERU0. GOUT1	CCU40. OUT1		BCCU0. OUT8	SCU. VDROP		CCU40.IN1 C						
P0.2	ERU0. P0OUT2	LEDTS0. LINE5	ERU0. GOUT2	CCU40. OUT2		VADC0. EMUX02			CCU40.IN2 C						
P0.3	ERU0. P0OUT3	LEDTS0. LINE4	ERU0. GOUT3	CCU40. OUT3		VADC0. EMUX01			CCU40.IN3 C						
P0.4	BCCU0. OUT0	LEDTS0. LINE3	LEDTS0. COL3	CCU40. OUT1		VADC0. EMUX00	WWDT. SERVICE_ OUT								
P0.5	BCCU0. OUT1	LEDTS0. LINE2	LEDTS0. COL2	CCU40. OUT0		ACMP2. OUT									
P0.6	BCCU0. OUT2	LEDTS0. LINE1	LEDTS0. COL1	CCU40. OUT0		USIC0_CH 1.MCLKOU T	USIC0_CH 1.DOUT0		CCU40.IN0 B			USIC0_CH 1.DX0C			
P0.7	BCCU0. OUT3	LEDTS0. LINE0	LEDTS0. COL0	CCU40. OUT1		USIC0_CH 0.SCLKOU T	USIC0_CH 1.DOUT0		CCU40.IN1 B			USIC0_CH 0.DX1C	USIC0_CH 1.DX0D	USIC0_CH 1.DX1C	
P0.8	BCCU0. OUT4	LEDTS1. LINE0	LEDTS0. COLA	CCU40. OUT2		USIC0_CH 0.SCLKOU T	USIC0_CH 1.SCLKOU T		CCU40.IN2 B			USIC0_CH 0.DX1B	USIC0_CH 1.DX1B		
P0.9	BCCU0. OUT5	LEDTS1. LINE1	LEDTS0. COL6	CCU40. OUT3		USIC0_CH 0.SELO0	USIC0_CH 1.SELO0		CCU40.IN3 B			USIC0_CH 0.DX2B	USIC0_CH 1.DX2B		
P0.10	BCCU0. OUT6	LEDTS1. LINE2	LEDTS0. COL5	ACMP0. OUT		USIC0_CH 0.SELO1	USIC0_CH 1.SELO1					USIC0_CH 0.DX2C	USIC0_CH 1.DX2C		
P0.11	BCCU0. OUT7	LEDTS1. LINE3	LEDTS0. COL4	USIC0_CH 0.MCLKOU T		USIC0_CH 0.SELO2	USIC0_CH 1.SELO2					USIC0_CH 0.DX2D	USIC0_CH 1.DX2D		
P0.12	BCCU0. OUT6	LEDTS1. LINE4	LEDTS0. COL3	LEDTS1. COL3		USIC0_CH 0.SELO3		BCCU0. TRAPINA	CCU40.IN0 A	CCU40.IN1 A	CCU40.IN2 A	CCU40.IN3 A	USIC0_CH 0.DX2E		
P0.13	WWDT. SERVICE_ OUT	LEDTS1. LINE5	LEDTS0. COL2	LEDTS1. COL2		USIC0_CH 0.SELO4						USIC0_CH 0.DX2F			
P0.14	BCCU0. OUT7	LEDTS1. LINE6	LEDTS0. COL1	LEDTS1. COL1		USIC0_CH 0.DOUT0	USIC0_CH 0.SCLKOU T					USIC0_CH 0.DX0A	USIC0_CH 0.DX1A		

**Table 10 Hardware Controlled I/O Functions**

Function	Outputs		Inputs		Pull Control			
	HWO0	HWO1	HWI0	HWI1	HW0_PD	HW0_PU	HW1_PD	HW1_PU
P1.3		USIC0_CH0.DOUT3		USIC0_CH0.HWIN3	BCCU0.OUT5	BCCU0.OUT5		
P1.4					BCCU0.OUT6	BCCU0.OUT6		
P1.5					BCCU0.OUT7	BCCU0.OUT7		
P1.6					BCCU0.OUT8	BCCU0.OUT8		
P2.0					BCCU0.OUT1	BCCU0.OUT1		
P2.1					BCCU0.OUT6	BCCU0.OUT6		
P2.2					BCCU0.OUT0	BCCU0.OUT0	CCU40.OUT3	CCU40.OUT3
P2.3					ACMP2.OUT	ACMP2.OUT		
P2.4					BCCU0.OUT8	BCCU0.OUT8		
P2.5					ACMP1.OUT	ACMP1.OUT		
P2.6					BCCU0.OUT2	BCCU0.OUT2	CCU40.OUT3	CCU40.OUT3
P2.7					BCCU0.OUT8	BCCU0.OUT8	CCU40.OUT3	CCU40.OUT3
P2.8					BCCU0.OUT1	BCCU0.OUT1	CCU40.OUT2	CCU40.OUT2
P2.9					BCCU0.OUT7	BCCU0.OUT7	CCU40.OUT2	CCU40.OUT2
P2.10					BCCU0.OUT4	BCCU0.OUT4		
P2.11					BCCU0.OUT5	BCCU0.OUT5		



### **3 Electrical Parameter**

This section provides the electrical parameter which are implementation-specific for the XMC1200.

#### **3.1 General Parameters**

##### **3.1.1 Parameter Interpretation**

The parameters listed in this section represent partly the characteristics of the XMC1200 and partly its requirements on the system. To aid interpreting the parameters easily when evaluating them for a design, they are indicated by the abbreviations in the "Symbol" column:

- **CC**  
Such parameters indicate **C**ontroller **C**haracteristics, which are distinctive feature of the XMC1200 and must be regarded for a system design.
- **SR**  
Such parameters indicate **S**ystem **R**equirements, which must be provided by the application system in which the XMC1200 is designed in.

### 3.1.2 Absolute Maximum Ratings

Stresses above the values listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

**Table 11 Absolute Maximum Rating Parameters**

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min	Typ.	Max.		
Junction temperature	$T_J$	SR	-40	–	115	°C	–
Storage temperature	$T_{ST}$	SR	-40	–	125	°C	–
Voltage on power supply pin with respect to $V_{SSP}$	$V_{DDP}$	S	-0.3	–	6	V	–
Voltage on any pin with respect to $V_{SSP}$	$V_{IN}$	SR	-0.5	–	$V_{DDP} + 0.5$ or max. 6	V	whichever is lower
Voltage on any analog input pin with respect to $V_{SSP}$	$V_{AIN}$ $V_{AREF}$	SR	-0.5	–	$V_{DDP} + 0.5$ or max. 6	V	–
Input current on any pin during overload condition	$I_{IN}$	SR	-10	–	10	mA	–
Absolute maximum sum of all input currents during overload condition	$\Sigma I_{IN}$	SR	-50	–	+50	mA	–
Analog comparator input voltage	$V_{CM}$	SR	-0.3	–	$V_{DDP} + 0.3$	V	–

### 3.1.3 Pin Reliability in Overload

When receiving signals from higher voltage devices, low-voltage devices experience overload currents and voltages that go beyond their own IO power supplies specification.

**Table 12** defines overload conditions that will not cause any negative reliability impact if all the following conditions are met:

- full operation life-time is not exceeded
- **Operating Conditions** are met for
  - pad supply levels ( $V_{DDP}$ )
  - temperature

## Electrical Parameter

If a pin current is outside of the **Operating Conditions** but within the overload conditions, then the parameters of this pin as stated in the Operating Conditions can no longer be guaranteed. Operation is still possible in most cases but with relaxed parameters.

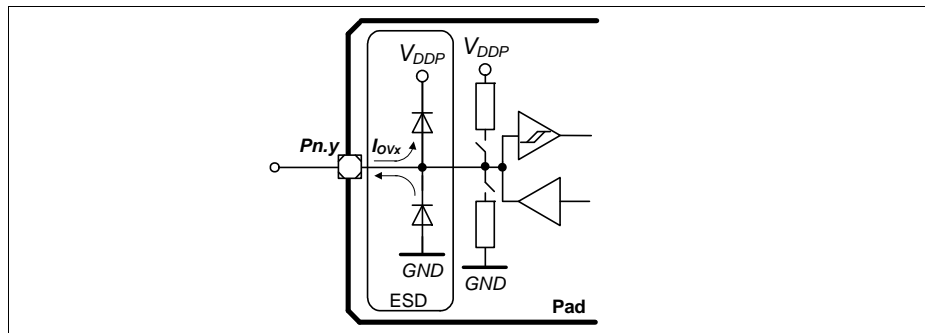
*Note: An overload condition on one or more pins does not require a reset.*

*Note: A series resistor at the pin to limit the current to the maximum permitted overload current is sufficient to handle failure situations like short to battery.*

**Table 12 Overload Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input current on any port pin during overload condition	$I_{OV}$ SR	-5	—	5	mA	
Absolute sum of all input circuit currents during overload condition	$I_{OVS}$ SR	—	—	25	mA	

**Figure 10** shows the path of the input currents during overload via the ESD protection structures. The diodes against  $V_{DDP}$  and ground are a simplified representation of these ESD protection structures.



**Figure 10 Input Overload Current via ESD structures**

**Table 13** and **Table 14** list input voltages that can be reached under overload conditions. Note that the absolute maximum input voltages as defined in the **Absolute Maximum Ratings** must not be exceeded during overload.

### 3.1.4 Operating Conditions

The following operating conditions must not be exceeded in order to ensure correct operation and reliability of the XMC1200. All parameters specified in the following tables refer to these operating conditions, unless noted otherwise.

**Table 15 Operating Conditions Parameters**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Ambient Temperature	$T_A$ SR	-40	–	85	°C	Temp. Range F
		-40	–	105	°C	Temp. Range X
Digital supply voltage <sup>1)</sup>	$V_{DDP}$ SR	1.8	–	5.5	V	
MCLK Frequency	$f_{MCLK}$ CC	–	–	33.2	MHz	CPU clock
PCLK Frequency	$f_{PCLK}$ CC	–	–	66.4	MHz	Peripherals clock
Short circuit current of digital outputs	$I_{SC}$ SR	-5	–	5	mA	
Absolute sum of short circuit currents of the device	$\Sigma I_{SC\_D}$ SR	–	–	25	mA	

1) See also the Supply Monitoring thresholds, [Chapter 3.3.2](#).

## 3.2 DC Parameters

### 3.2.1 Input/Output Characteristics

**Table 16** provides the characteristics of the input/output pins of the XMC1200.

*Note: These parameters are not subject to production test, but verified by design and/or characterization.*

*Note: Unless otherwise stated, input DC and AC characteristics, including peripheral timings, assume that the input pads operate with the standard hysteresis.*

**Table 16 Input/Output Characteristics (Operating Conditions apply)**

Parameter	Symbol		Limit Values		Unit	Test Conditions
			Min.	Max.		
Output low voltage on port pins (with standard pads)	$V_{OLP}$	CC	–	1.0	V	$I_{OL} = 11 \text{ mA}$ (5 V) $I_{OL} = 7 \text{ mA}$ (3.3 V)
			–	0.4	V	$I_{OL} = 5 \text{ mA}$ (5 V) $I_{OL} = 3.5 \text{ mA}$ (3.3 V)
Output low voltage on high current pads	$V_{OLP1}$	CC	–	1.0	V	$I_{OL} = 50 \text{ mA}$ (5 V) $I_{OL} = 25 \text{ mA}$ (3.3 V)
			–	0.32	V	$I_{OL} = 10 \text{ mA}$ (5 V)
			–	0.4	V	$I_{OL} = 5 \text{ mA}$ (3.3 V)
Output high voltage on port pins (with standard pads)	$V_{OHP}$	CC	$V_{DDP} - 1.0$	–	V	$I_{OH} = -10 \text{ mA}$ (5 V) $I_{OH} = -7 \text{ mA}$ (3.3 V)
			$V_{DDP} - 0.4$	–	V	$I_{OH} = -4.5 \text{ mA}$ (5 V) $I_{OH} = -2.5 \text{ mA}$ (3.3 V)
Output high voltage on high current pads	$V_{OHP1}$	CC	$V_{DDP} - 0.32$	–	V	$I_{OH} = -6 \text{ mA}$ (5 V)
			$V_{DDP} - 1.0$	–	V	$I_{OH} = -8 \text{ mA}$ (3.3 V)
			$V_{DDP} - 0.4$	–	V	$I_{OH} = -4 \text{ mA}$ (3.3 V)
Input low voltage on port pins (Standard Hysteresis)	$V_{ILPS}$	SR	–	$0.19 \times V_{DDP}$	V	CMOS Mode (5 V, 3.3 V & 2.2 V)
Input high voltage on port pins (Standard Hysteresis)	$V_{IHPS}$	SR	$0.7 \times V_{DDP}$	–	V	CMOS Mode (5 V, 3.3 V & 2.2 V)

**Electrical Parameter**
**Table 16 Input/Output Characteristics (Operating Conditions apply) (cont'd)**

Parameter	Symbol		Limit Values		Unit	Test Conditions
			Min.	Max.		
Pin capacitance (digital inputs/outputs)	$C_{IO}$	CC	–	10	pF	
Pull-up resistor on port pins	$R_{PUP}$	CC	20	50	kohm	$V_{IN} = V_{SSP}$
Pull-down resistor on port pins	$R_{PDP}$	CC	20	50	kohm	$V_{IN} = V_{DDP}$
Input leakage current <sup>9)</sup>	$I_{OZP}$	CC	-1	1	μA	$0 < V_{IN} < V_{DDP}$ , $T_A \leq 105\text{ °C}$
Voltage on any pin during $V_{DDP}$ power off	$V_{PO}$	SR	–	0.3	V	<sup>10)</sup>
Maximum current per pin (excluding P1, $V_{DDP}$ and $V_{SS}$ )	$I_{MP}$	SR	-10	11	mA	–
Maximum current per high current pins	$I_{MP1A}$	SR	-10	50	mA	–
Maximum current into $V_{DDP}$ (TSSOP28/16, VQFN24)	$I_{MVDD1}$	SR	–	130	mA	<sup>10)</sup>
Maximum current into $V_{DDP}$ (TSSOP38, VQFN40)	$I_{MVDD2}$	SR	–	260	mA	<sup>10)</sup>
Maximum current out of $V_{SS}$ (TSSOP28/16, VQFN24)	$I_{MVSS1}$	SR	–	130	mA	<sup>10)</sup>
Maximum current out of $V_{SS}$ (TSSOP38, VQFN40)	$I_{MVSS2}$	SR	–	260	mA	<sup>10)</sup>

1) Rise/Fall time parameters are taken with 10% - 90% of supply.

2) Additional rise/fall time valid for  $C_L = 50\text{ pF}$  -  $C_L = 100\text{ pF}$  @ 0.150 ns/pF at 5 V supply voltage.

3) Additional rise/fall time valid for  $C_L = 50\text{ pF}$  -  $C_L = 100\text{ pF}$  @ 0.205 ns/pF at 3.3 V supply voltage.

4) Additional rise/fall time valid for  $C_L = 50\text{ pF}$  -  $C_L = 100\text{ pF}$  @ 0.445 ns/pF at 1.8 V supply voltage.

5) Additional rise/fall time valid for  $C_L = 50\text{ pF}$  -  $C_L = 100\text{ pF}$  @ 0.225 ns/pF at 5 V supply voltage.

6) Additional rise/fall time valid for  $C_L = 50\text{ pF}$  -  $C_L = 100\text{ pF}$  @ 0.288 ns/pF at 3.3 V supply voltage.

7) Additional rise/fall time valid for  $C_L = 50\text{ pF}$  -  $C_L = 100\text{ pF}$  @ 0.588 ns/pF at 1.8 V supply voltage.

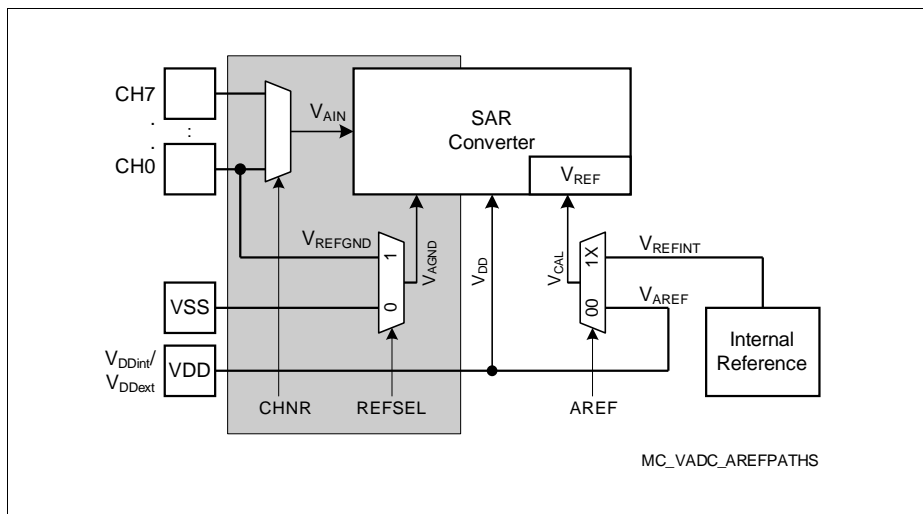
### 3.2.2 Analog to Digital Converters (ADC)

**Table 17** shows the Analog to Digital Converter (ADC) characteristics.

*Note: These parameters are not subject to production test, but verified by design and/or characterization.*

**Table 17 ADC Characteristics (Operating Conditions apply)<sup>1)</sup>**

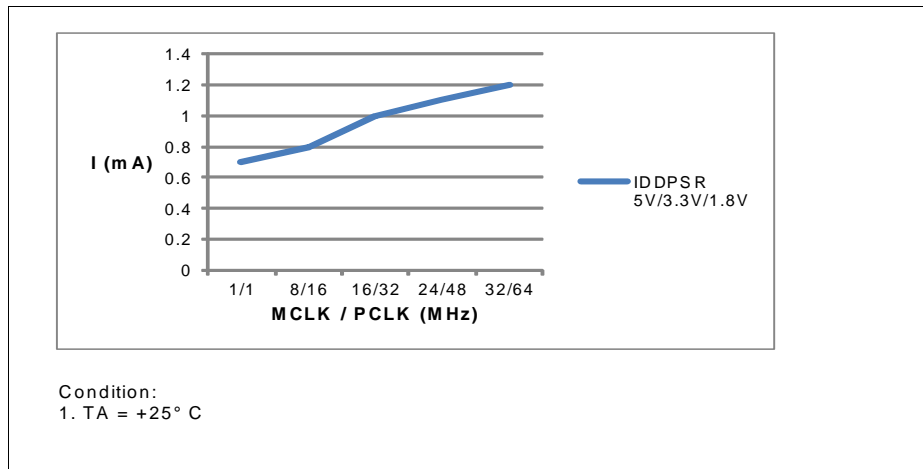
Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Supply voltage range (internal reference)	$V_{DD\_int}$ SR	2.0	—	3.0	V	SHSCFG.AREF = 11 <sub>B</sub> CALCTR.CALGNSTC = 0C <sub>H</sub>
		3.0	—	5.5	V	SHSCFG.AREF = 10 <sub>B</sub>
Supply voltage range (external reference)	$V_{DD\_ext}$ SR	3.0	—	5.5	V	SHSCFG.AREF = 00 <sub>B</sub>
Analog input voltage range	$V_{AIN}$ SR	$V_{SSP} - 0.05$	—	$V_{DDP} + 0.05$	V	
Auxiliary analog reference ground	$V_{REFGND}$ SR	$V_{SSP} - 0.05$	—	1.0	V	G0CH0
		$V_{SSP} - 0.05$	—	0.2	V	G1CH0
Internal reference voltage (full scale value)	$V_{REFINT}$ CC	5			V	
Switched capacitance of an analog input	$C_{AINS}$ CC	—	1.2	2	pF	GNCTRxz.GAINy = 00 <sub>B</sub> (unity gain)
		—	1.2	2	pF	GNCTRxz.GAINy = 01 <sub>B</sub> (gain g1)
		—	4.5	6	pF	GNCTRxz.GAINy = 10 <sub>B</sub> (gain g2)
		—	4.5	6	pF	GNCTRxz.GAINy = 11 <sub>B</sub> (gain g3)
Total capacitance of an analog input	$C_{AINT}$ CC	—	—	10	pF	
Total capacitance of the reference input	$C_{AREFT}$ CC	—	—	10	pF	



**Figure 11 ADC Voltage Supply**



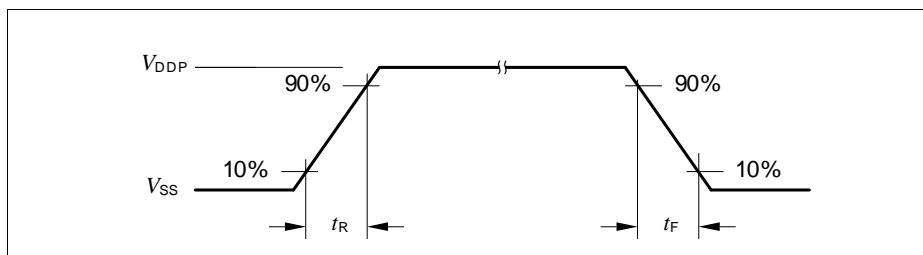
**Figure 15** shows typical graphs for sleep mode current for  $V_{DDP} = 5V$ ,  $V_{DDP} = 3.3V$ ,  $V_{DDP} = 1.8V$  across different clock frequencies.



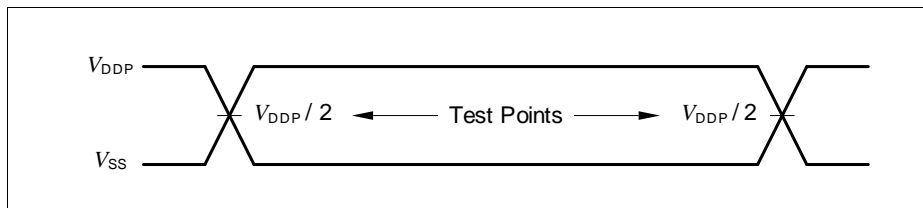
**Figure 15** Sleep mode, peripherals clocks disabled, Flash powered down:  
 Supply current  $I_{DDPSR}$  over supply voltage  $V_{DDP}$  for different clock frequencies

### 3.3 AC Parameters

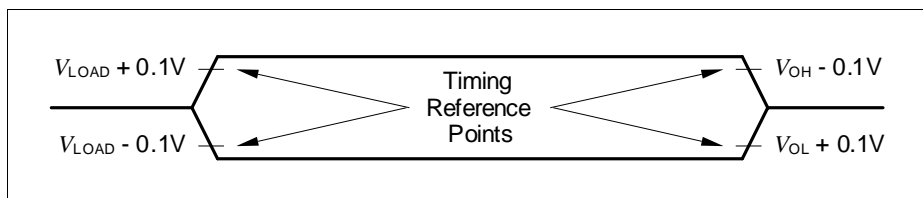
#### 3.3.1 Testing Waveforms



**Figure 16 Rise/Fall Time Parameters**



**Figure 17 Testing Waveform, Output Delay**



**Figure 18 Testing Waveform, Output High Impedance**

### 3.3.2 Power-Up and Supply Monitoring Characteristics

**Table 24** provides the characteristics of the power-up and supply monitoring in XMC1200.

The guard band between the lowest valid operating voltage and the brownout reset threshold provides a margin for noise immunity and hysteresis. The electrical parameters may be violated while  $V_{DDP}$  is outside its operating range.

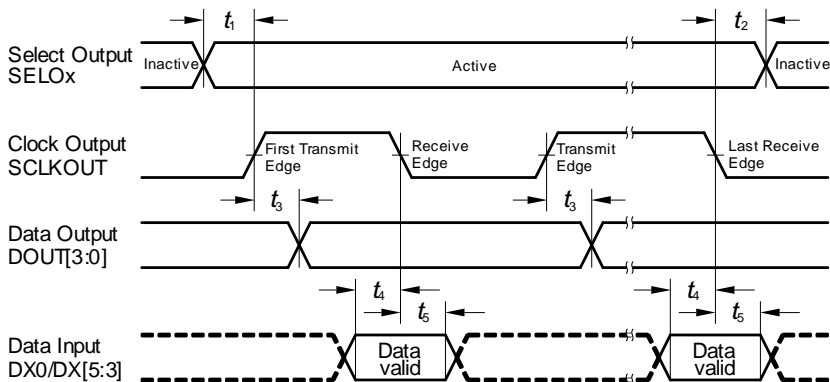
The brownout detection triggers a reset within the defined range. The prewarning detection can be used to trigger an early warning and issue corrective and/or fail-safe actions in case of a critical supply voltage drop.

*Note: These parameters are not subject to production test, but verified by design and/or characterization.*

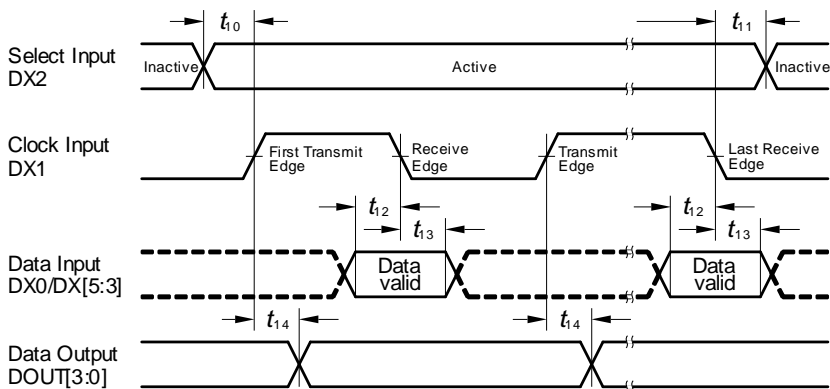
**Table 24 Power-Up and Supply Monitoring Parameters (Operating Conditions apply)<sup>1)</sup>**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
$V_{DDP}$ ramp-up time	$t_{RAMPUP}$ SR	$V_{DDP}/S_{VDDPrise}$	–	$10^7$	μs	
$V_{DDP}$ slew rate	$S_{VDDPOP}$ SR	0	–	0.1	V/μs	Slope during normal operation
	$S_{VDDP10}$ SR	0	–	10	V/μs	Slope during fast transient within +/- 10% of $V_{DDP}$
	$S_{VDDPrise}$ SR	0	–	10	V/μs	Slope during power-on or restart after brownout event
	$S_{VDDPfall}$ <sup>2)</sup> SR	0	–	0.25	V/μs	Slope during supply falling out of the +/-10% limits <sup>3)</sup>
$V_{DDP}$ prewarning voltage	$V_{DDPPW}$ CC	2.1	2.25	2.4	V	ANAVDEL.VDEL_SELECT = 00 <sub>B</sub>
		2.85	3	3.15	V	ANAVDEL.VDEL_SELECT = 01 <sub>B</sub>
		4.2	4.4	4.6	V	ANAVDEL.VDEL_SELECT = 10 <sub>B</sub>

### Master Mode Timing



### Slave Mode Timing



Transmit Edge: with this clock edge transmit data is shifted to transmit data output

Receive Edge: with this clock edge receive data at receive data input is latched

Drawn for BRGH.SCLKCFG = 00<sub>b</sub>. Also valid for for SCLKCFG = 01<sub>b</sub> with inverted SCLKOUT signal

USIC\_SSC\_TMGX.VSD

**Figure 22 USIC - SSC Master/Slave Mode Timing**

*Note: This timing diagram shows a standard configuration, for which the slave select signal is low-active, and the serial clock signal is not shifted and not inverted.*

**Package and Reliability**

The difference between junction temperature and ambient temperature is determined by

$$\Delta T = (P_{\text{INT}} + P_{\text{IOSTAT}} + P_{\text{IODYN}}) \times R_{\Theta JA}$$

The internal power consumption is defined as

$$P_{\text{INT}} = V_{\text{DDP}} \times I_{\text{DDP}} \text{ (switching current and leakage current).}$$

The static external power consumption caused by the output drivers is defined as

$$P_{\text{IOSTAT}} = \Sigma((V_{\text{DDP}} - V_{\text{OH}}) \times I_{\text{OH}}) + \Sigma(V_{\text{OL}} \times I_{\text{OL}})$$

The dynamic external power consumption caused by the output drivers ( $P_{\text{IODYN}}$ ) depends on the capacitive load connected to the respective pins and their switching frequencies.

If the total power dissipation for a given system configuration exceeds the defined limit, countermeasures must be taken to ensure proper system operation:

- Reduce  $V_{\text{DDP}}$ , if possible in the system
- Reduce the system frequency
- Reduce the number of output pins
- Reduce the load on active output drivers